The Silicon Vertex Detector of the Belle II Experiment

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Abstract

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- The Silicon Vertex Detector (SVD) is a part of the vertex detector in the
- Belle II experiment at the SuperKEKB collider (KEK, Japan). Since the start
- of data taking in spring 2019, the SVD has been operating stably and reliably

with a high signal-to-noise ratio and hit efficiency, achieving good spatial resolution and high track reconstruction efficiency. The hit occupancy, which mostly comes from the beam-related background, is currently about 0.5% in the innermost layer, causing no impact on the SVD performance. In anticipation of the operation at higher luminosity in the next years, two strategies to sustain 47 the tracking performance in future high beam background conditions have been 48 developed and tested on data. One is to reduce the number of signal waveform samples to decrease dead time, data size, and occupancy. The other is to utilize the good hit-time resolution to reject the beam background hits. We also mea-51 sured the radiation effects on the sensor current, strip noise, and full depletion voltage caused during the first two and a half years of operation. The results 53 show no detrimental effect on the SVD performance.

55 Keywords: Silicon strip detector, Vertex detector, Tracking detector, Belle II

56 1. Introduction

The Belle II experiment [1] aims to probe new physics beyond the Standard 57 Model in high-luminosity e⁺e⁻ collisions at the SuperKEKB collider (KEK, Japan) [2]. SuperKEKB consists of the following components: injector LINAC, positron damping ring, and main storage ring with the electron and positron beamlines. The Belle II detector is located at the interaction point (IP) of the two beamlines. The main collision energy in the center-of-mass system is 10.58 GeV on the $\Upsilon(4S)$ resonance, which enables various physics programs 63 based on the large samples of B mesons, τ leptons, and D mesons. Also, the asymmetric energy of the 7 GeV electron beam and 4 GeV positron beam is adopted for time-dependent CP violation measurements. The target of SuperKEKB is to accumulate an integrated luminosity of 50 ab⁻¹ with peak lu-67 minosity of about 6×10^{35} cm⁻²s⁻¹. In June 2021, SuperKEKB recorded the wolrd's highest instantaneous luminosity of 3.1×10^{34} cm⁻²s⁻¹. The data accumulated before July 2021 corresponds to an integrated luminosity of 213 fb $^{-1}$. 70 The Vertex Detector (VXD) is the innermost detector in the Belle II detector 71

system. The VXD has six layers: the inner two layers (layers 1 and 2) are the Pixel Detector (PXD), and the outer four layers (layers 3 to 6) are the Silicon Vertex Detector (SVD). The schematic cross-sectional view of the VXD is shown in Fig. 1. The PXD consists of DEPFET pixel sensors, and its innermost radius is 1.4 cm from the IP. A detailed description of the SVD appears in Sec. 2.

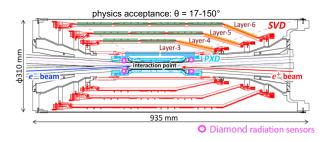


Figure 1: Schematic cross-sectional view of the VXD. The SVD is in red, the PXD in light-blue, and the IP beam pipe diamonds in pink circles. The locations of the three types of DSSDs are indicated by boxes in three colors: blue for small sensors, green for large sensors, and orange for trapezoidal sensors as described in Tab. 1.

Besides the VXD, diamond sensors [3] are mounted on the IP beam pipe and the bellows pipes outside of the VXD. The pink circles in Fig. 1 indicate the locations of the diamond sensors on the IP beam pipe. They measure the dose rates in these locations. The measured doses are used to estimate the dose in the SVD. They also send beam abort requests to SuperKEKB if the radiation level gets too high to avoid severe damage to the detector.

2. Belle II Silicon Vertex Detector

The SVD is crucial for extrapolating the tracks to the PXD. This task is
essential for measuring the decay vertices with the PXD and pointing at a
region-of-interest limiting the PXD readout volume. Also, the SVD plays a
critical role in the decay vertex measurement in the case of long-lived particles
like K_S mesons, which decay inside the SVD volume. Other roles of the SVD
are the standalone track reconstruction of low-momentum charged particles and
their particle identification using ionization energy deposits.

The SVD [4] consists of four layers of double-sided silicon strip detectors 91 (DSSDs). The material budget of the SVD is about 0.7% of a radiation length per layer. The aluminum readout strips are AC-coupled to every other n/pside strips (electrodes) on the n-type substrate over the silicon oxide layer. On each DSSD plane, a local coordinate is defined with u and v: u-axis along n-side strips and v-axis perpendicular to u-axis. In other words, p-side strips and n-side 96 strips provide u and v information, respectively. In the cylindrical coordinate, ucorresponds to $r-\varphi$ information and v corresponds to z information. The SVD consists of three types of sensors: "small" sensors in layer 3, "large" sensors in 99 the barrel region of layers 4, 5, and 6, and "trapezoidal" sensors in the forward 100 region of layers 4, 5, and 6, which is slanted. They are indicated in blue, green, 101 and orange boxes in Fig. 1. The dimensions for these three types of sensors are 102 summarized in Tab. 1. The sensors are manufactured by two companies: the small and large sensors by Hamamatsu and trapezoidal sensors by Micron. The 104 full depletion voltage is 60 V for Hamamatsu sensors, 20 V for Micron sensors; 105 both types of sensors are operated at 100 V. In total, 172 sensors are assembled, 106 corresponding to a total sensor area of 1.2 m² and 224,000 readout strips.

	Small	Large	Trapezoidal
No. of u/p-strips	768	768	768
u/p-strip pitch	$50~\mu\mathrm{m}$	$75~\mu\mathrm{m}$	$5075~\mu\mathrm{m}$
No. of v/n-strips	768	512	512
v/n-strip pitch	$160~\mu\mathrm{m}$	$240~\mu\mathrm{m}$	$240~\mu\mathrm{m}$
Thickness	$320~\mu\mathrm{m}$	$300~\mu\mathrm{m}$	$300~\mu\mathrm{m}$
Manufacturer	Hamamatsu		Micron

Table 1: Table of dimensions for three types of sensors. Only readout strips are taken into account for number of strips and strip pitch.

The front-end ASIC used in the SVD is APV25 [5], which was originally developed for the CMS silicon tracker. The APV25 is radiation hard for a dose up to 100 Mrad radiation. It has 128 channel inputs and shapers for

each channel with a shaping time of about 50 ns. For the SVD, the APV25 is 111 operated in "multi-peak" mode. The mechanism of the data sampling in the 112 multi-peak mode is explained in Fig. 2. The chip samples the height of the 113 signal waveform with the 32 MHz clock and stores each sample's information 114 in an analog ring buffer. Since the bunch-crossing frequency is eight times 115 faster than the sampling clock, the stored samples are not synchronous to the 116 beam collision, in contrast to CMS, which motivates operation in the multi-117 peak mode. In the present readout configuration (the six-samples mode), at every reception of the Belle II global Level-1 trigger, the chip reads out six 119 successive samples of the signal waveform stored in the buffers. The six-samples 120 mode offers enough time window $(6/32 \text{ MHz}^{-1} = 187 \text{ ns})$ to accommodate large 121 timing shifts of the trigger. In preparation for operation with higher luminosity, 122 where background occupancy, trigger dead-time, and the data size increase, we developed the three/six-mixed acquisition mode (mixed-mode). The mixed-124 mode is a new method to read out the signal samples from the APV25, in 125 which the number of the samples changes between three and six in each event, 126 depending on the timing precision of each Level-1 trigger signal in that event. 127 For triggers with good timing precision, three-samples data are read out and the 128 data have half time window and half data size compared to ones of six-samples 129 data, resulting in the reduction of the effect due to higher luminosity. This 130 functionality was already implemented in the running system and confirmed by 131 a few hours of smooth physics data-taking. Before we start to use the mixedmode, the effect on the performance due to the change of the acquisition mode 133 is to be assessed. As the first step, the effect in the hit efficiency was evaluated 134 as described in Sec. 3. 135

The APV25 chips are mounted on each middle sensor (chip-on-sensor concept) with thermal isolation foam in between. The merit of this concept is shorter signal propagation length, leading to smaller capacitance of the signal line and hence reduced noise level. To minimize the material budget the APV25 chips on the sensor are thinned down to $100 \ \mu m$. APV25s are mounted on a single side of the sensor and readout of the signals is from the other side via

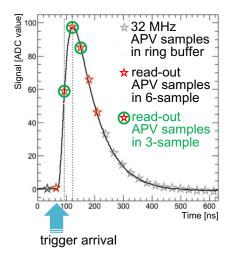


Figure 2: Sampling in the "multi-peak" mode of APV25. The black line shows the signal waveform after the CR-RC shaper circuit. The stars show the sampled signal height recorded in the analog ring buffer according to the 32 MHz sampling clock. The red stars indicate the six successive samples read out at the trigger reception in the six-samples mode. The red stars with a green circle indicate the samples read out in the three-samples acquisition.

wrapped flexible printed circuits. The power consumption of the APV25 chip is 0.4 W/chip and in total 700 W in the entire SVD. The chips are chilled by 143 bi-phase -20° C CO₂.

3. Performance

The SVD was combined with the PXD to complete the VXD assembly in 146 October 2018, and the VXD was installed to the Belle II detector system in November 2018. Since March 2019, the SVD has been operating reliably and smoothly for two and a half years, without any major problems. The total 149 fraction of masked strips is about 1%. There was only one issue where one 150 APV25 chip (out of 1,748 chips) was disabled during the spring of 2019, which 151 was remediated by reconnecting a cable in the summer of 2019. 152 The SVD has also demonstrated stable and excellent performance [6]. The 153

hit efficiency is continuously over 99% in most of the sensors. The cluster 154

charge distributions are also reasonable. On the u/p-side, the most probable values agree with the calculated charge amount induced by MIPs within the uncertainty in calibration. On the v/n-side, 10-30% of the collected charge is lost compared to MIP due to the smaller inter-strip capacitance of the floating strips with larger strip pitches than the u/p-side. The most probable values of the cluster signal-to-noise ratio distributions range from 13 to 30.

We measured the cluster position resolution by analyzing the $e^+e^- \to \mu^+\mu^-$ data [7]. The cluster position resolution is estimated from the residual between the cluster position and the track position not biased by the target cluster after subtracting the effect of the track extrapolation error. The cluster position resolutions for different incident angles are shown in Fig. 3. For normal incident tracks, it agrees with the expectations from the strip pitch including floating strips. For tracks with an incident angle, it is expected to get a better resolution, which is indeed the case in the v/n-side results. However, this effect is not observed on the u/p-side, and the study is still ongoing to improve the cluster position estimation.

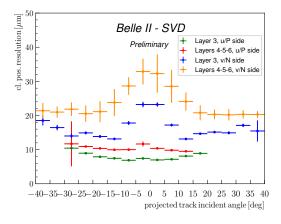


Figure 3: The SVD cluster position resolution depending on the projected track incident angle. The green (blue) plot shows the resolution in the u/p-side (n/v-side) of layer 3 sensors, and the red (yellow) one shows the u/p-side (n/v-side) of layers 4, 5, and 6 sensors.

The cluster hit-time resolution was also evaluated in hadron-event¹ data 171 using the reference event time estimated by the Central Drift Chamber (CDC) 172 outside of the SVD. The error on the event time, about 0.7 ns, was subtracted to evaluate the intrinsic SVD hit-time resolution. The resulting resolution is 174 2.9 ns on the u/p-side and 2.4 ns on the v/n-side. With such precise hit-175 time information, it is possible to reject off-time background hits efficiently. 176 The hit-time distributions for signal² and off-time background³ are shown in Fig. 4. The signal distribution has a narrow peak, while the background hit-time 178 distribution is broad and almost flat in the signal peak region. The separation 179 power of the hit-time is high, as expected. For example, if we reject hits with 180 the hit-time less than -38 ns in this plot, we can reject 46% of the background 181 hits while keeping 99% of the signal hits. The background rejection based on 182 the hit-time is essential to sustain the good tracking performance in the future 183 high beam background condition. 184

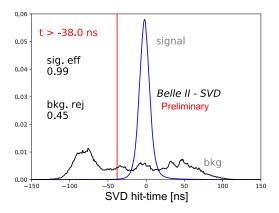


Figure 4: Example of the background hit rejection using hit-time. The blue distribution shows the signal, and the black distribution shows the off-time background. Assuming the hit-time cut at -38 ns, the signal hit efficiency of 99% and the background hit rejection of 46% are achieved.

¹The event with more than three good tracks and not like Bhabha scattering.

 $^{^{2}}$ The clusters found to be used in the tracks in the hadron events.

 $^{^3}$ The clusters in events triggered by delayed-Bhabha pseudo-random trigger.

The performance in three-samples data was compared with that in six-185 samples data to evaluate the performance in the mixed-mode. If the trigger 186 timing has no deviation, the three-samples data will show comparable performance to the six-samples data because the relevant part of the signal waveform 188 to evaluate the necessary signal properties, which are the signal height and the 189 signal timing, can be accommodated in the three-sample's time window. How-190 ever, when the trigger has a jitter and the timing shift happens, some part of 191 the signal waveform can be out of the three-sample's time window, and the 192 reconstruction performance deteriorates. We examined the effect on the hit ef-193 ficiency as a function of the trigger timing shift. The effect is evaluated by the 194 relative hit efficiency, which is defined as the ratio of the hit efficiency in the 195 three-samples data to the one in the six-samples data. For this study, the three-196 samples data are emulated in the offline analysis from the six-samples data by selecting consecutive three samples at fixed positions in the six samples. The 198 trigger timing shift is evaluated by the CDC event time. The resulting relative 199 efficiencies as a function of the trigger timing shift in the hadron-event data are 200 shown in Fig. 5. The decreasing trend is observed for the shift of the trigger 201 timing, as expected. As a result, the relative efficiency is over 99.9% for the 202 trigger timing shift within ± 30 ns. 203

²⁰⁴ 4. Beam-related background effects on SVD

The beam-related background increases the hit occupancy of the SVD, which 205 in turn degrades the tracking performance. Considering this performance degra-206 dation, we set the occupancy limit in layer 3 sensors to be about 3%, which will be loosened roughly by a factor of two after we apply the hit-time rejection 208 described in Sec. 3. With the current luminosity, the average hit occupancy in 200 layer 3 sensors is less than 0.5%. However, the projection of the hit occupancy 210 at the luminosity of 8×10^{35} cm⁻²s⁻¹ is about 3% in layer 3 sensors. The 211 projected occupancy comes from the Monte Carlo (MC) simulation scaled by the data/MC ratio determined from the beam background data of the current 213

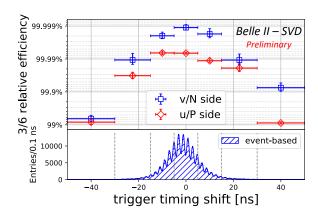


Figure 5: The relative hit efficiencies as a function of the trigger timing shift for v/n-side (blue square) and u/p-side(red diamond). The positive(negative) trigger timing shift corresponds to early(late) trigger timing.

beam optics. The corresponding dose is about $0.2 \,\mathrm{Mrad/smy}$, and the equivalent 1-MeV neutron fluence is about $5 \times 10^{11} \,\mathrm{n_{eq}/cm^2/smy}$ (smy: Snowmass Year $= 10^7 \,\mathrm{sec}$). The long-term extrapolation of the beam background is affected by large uncertainties from the optimization of collimator settings in MC and the future evolution of the beam injection background, which is not simulated. This uncertainty motivates the VXD upgrade which improves the tolerance of the hit rates and the radiation damage, and the technology assessment is ongoing for multiple sensor options.

From the measured dose on diamond sensors, the integrated radiation dose in the layer 3 mid-plane sensors, which are the most exposed in the SVD, is estimated to be 70 krad. The estimation is based on the correlation between the SVD occupancy and the diamonds dose. The estimated dose includes uncertainties of about 30% due to the unavailability of the appropriate trigger before December 2020. Assuming the dose/ $n_{\rm eq}$ fluence ratio of $2.3 \times 10^9 \ n_{\rm eq}/{\rm cm}^2/{\rm krad}$ from MC, 1-MeV equivalent neutron fluence is evaluated to be about $1.6 \times 10^{11} \ n_{\rm eq}/{\rm cm}^2$ in the first two and a half years.

The effect of the integrated dose on the sensor leakage current is measured, and the results show a clear linear correlation as in the upper plot of Fig. 6.

The slopes for all the sensors are summarized in the lower plot of Fig. 6. They are around $2-5 \,\mu\text{A/cm}^2/\text{Mrad}$. The large variations can be explained by tem-233 perature effects and the deviation of sensor-by-sensor dose from the average in each layer used in the estimation. The slopes are in the same order of magni-235 tude as previously measured in the BaBar experiment [8], 1 μ A/cm²/Mrad at 236 20°C. While the leakage current is increasing, the impact on the strip noise is 237 suppressed by the short shaping time (50 ns) in APV25. It is expected to be 238 comparable to the strip-capacitive noise only after 10 Mrad irradiation and not problematic for ten years where the integrated dose is estimated to be 2 Mrad. 240 The relation between the noise and the integrated dose is shown in Fig. 7. 241 The noise increase of 20–25% is observed in layer 3, but this does not affect the 242

performance of SVD. This noise increase is likely due to the radiation effects on the sensor surface. Fixed oxide charges on sensor surface increase non-linearly, enlarging inter-strip capacitance. The noise saturation is observed on the v/n-245 side and also starts to be seen on the u/p-side. This behavior agrees with the 246 increase of fixed oxide charges. 247

The full depletion voltage of the sensor is also a key property that can be 248 affected by the radiation damage. It can be measured from the v/n-side strip 249 noise, which suddenly decreases at the full depletion voltage because the sensor 250 substrate is n-type and thus the v/n-side strips can be fully isolated at the full depletion. From this measurement, reasonable full depletion voltages, which are 252 consistent with the values mentioned in Sec. 2, were confirmed, and so far no change in full depletion voltage is observed in the first two and a half years of operation, which is consistent with the expectation from low integrated neutron fluence of $1.6 \times 10^{11} \text{ n}_{eq}/\text{cm}^2$.

5. Conclusions 257

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The SVD has been taking data in Belle II since March 2019 smoothly and 258 reliably. The detector performance is excellent and agrees with expectations. We are ready to cope with the increased background during higher luminosity 260

running by rejecting the off-time background hits using hit-time and operating in the three/six-mixed acquisition mode. In the recent study, the efficiency loss in the three-samples data is confirmed to be less than 0.1% for the trigger timing shift within ± 30 ns. The observed first effects of radiation damage are also within expectation and do not affect the detector performance.

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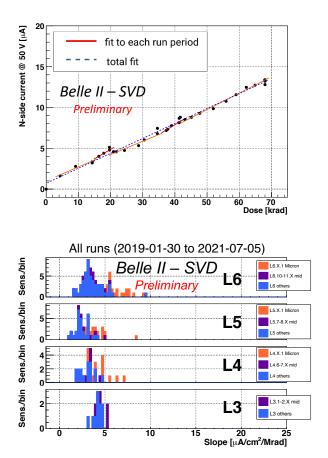


Figure 6: (upper) Effect of the integrated dose on the leakage current in the n/v-side of one sensor in layer 3. The slope is fitted for each run period (solid red line) and for all the runs (dashed blue line). (lower) The fit results of all the sensors for all runs. The sensors are classified as trapezoidal sensors in the forward region (Micron), sensors around the midplane, and the others.

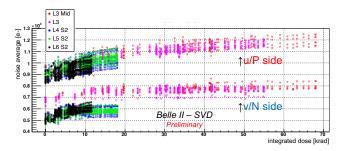


Figure 7: Effect of the integrated dose on the noise average in electron The clear increase is observed and saturated (or start to be saturated) for layer 3 sensors.